

Green Anti-solvent Processed Efficient Flexible Perovskite Solar Cells

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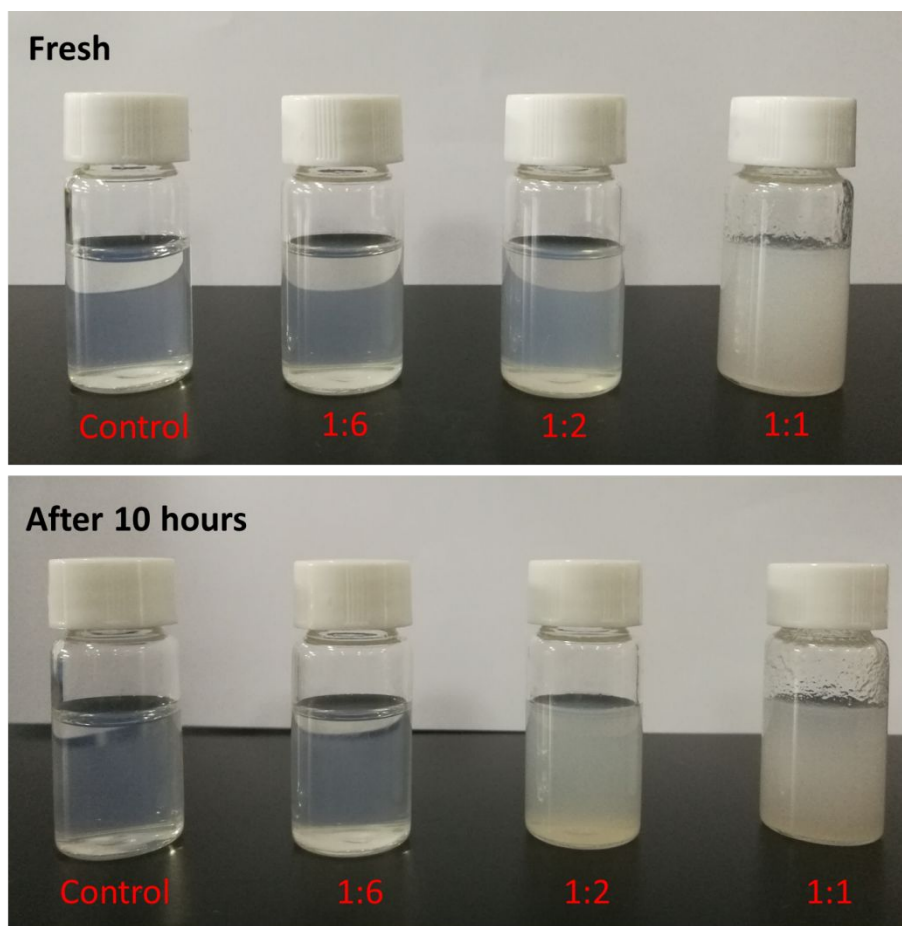


Figure S1. Photograph of SnO_2 solutions diluted by H_2O /TBA mixture with various volume ratios.

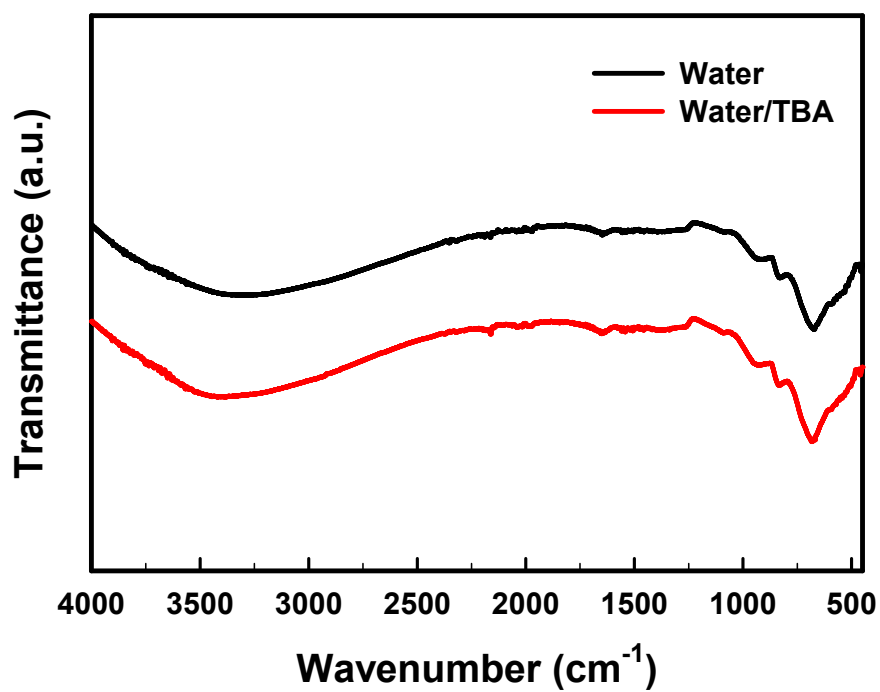


Figure S2. FTIR spectra of SnO₂ films prepared by SnO₂-colloid precursor diluted with water and water/TBA mixture.

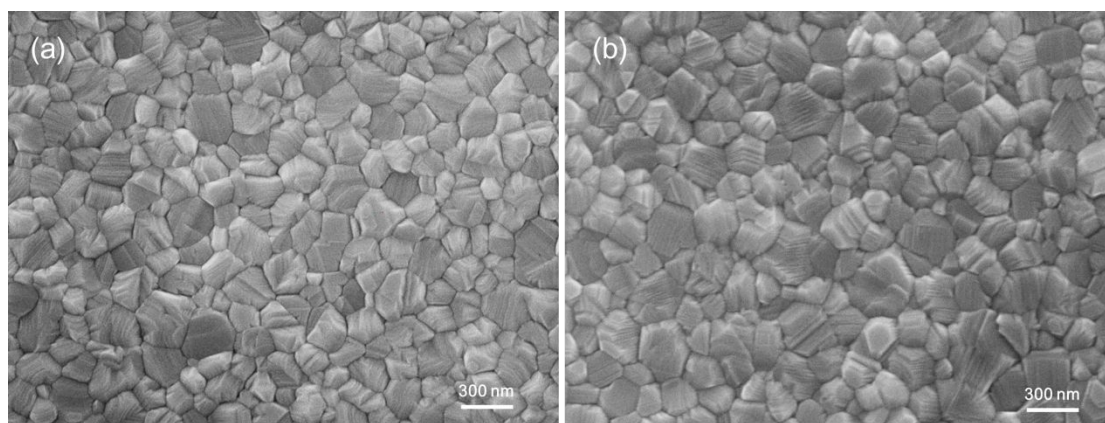


Figure S3. SEM images for perovskite films prepared on SnO_2 ETLs: (a) SnO_2 -control and (b) SnO_2 -TBA.

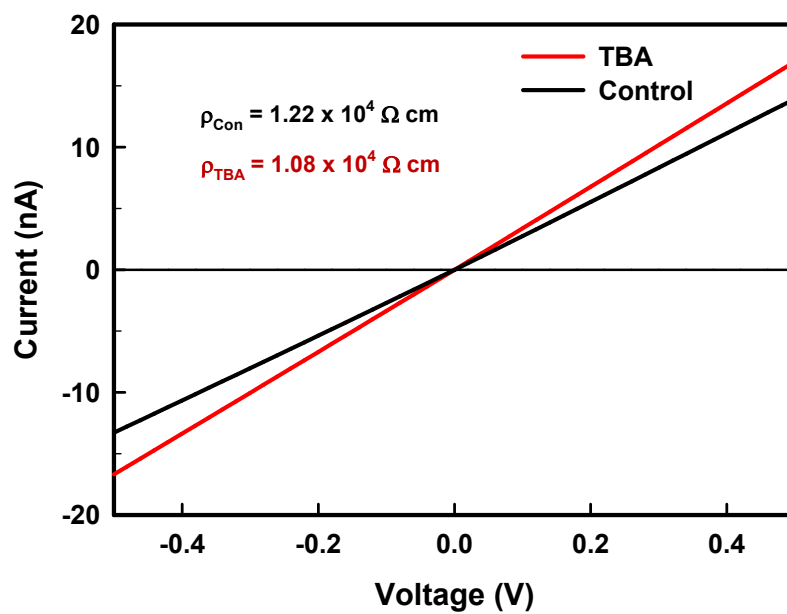


Figure S4. I-V characteristics and corresponding resistivity for SnO₂ ETLs.

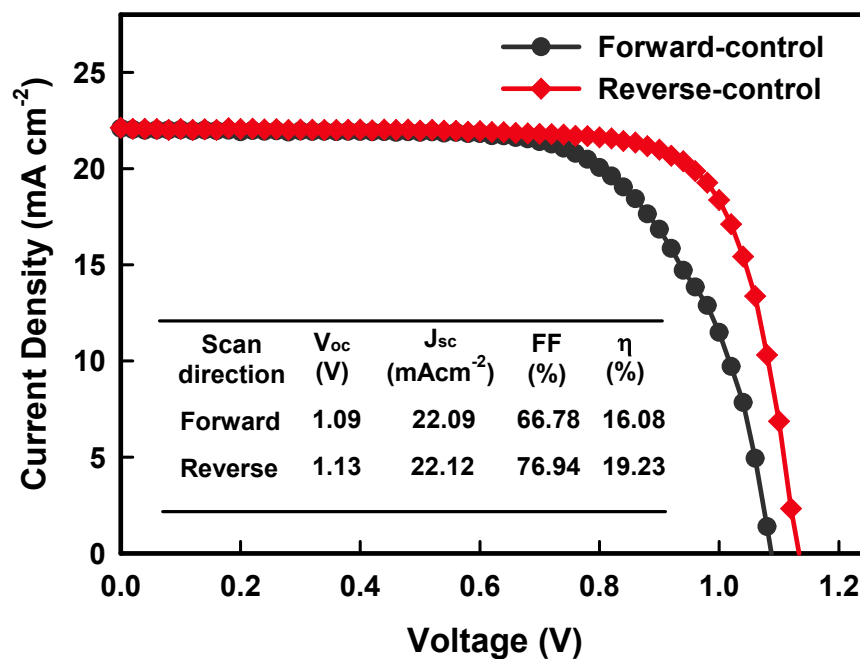


Figure S5. J–V curves for PSC on glass/ ITO based on SnO_2 -control under different scan directions. PSCs were fabricated by PhOMe green anti-solvent.

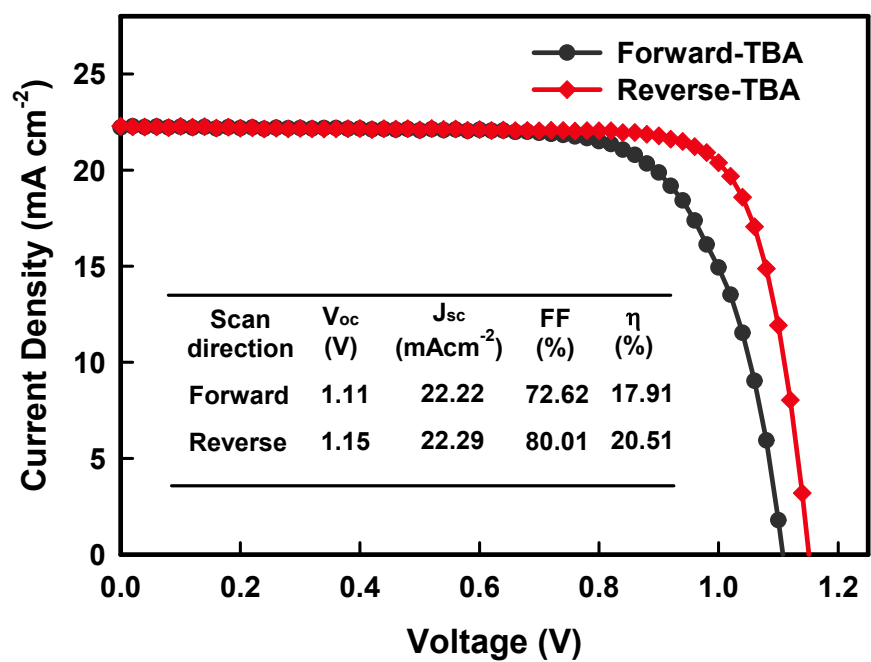


Figure S6. J–V curves for PSC on glass/ ITO based on SnO₂-TBA under different scan directions. PSCs were fabricated by PhOMe green anti-solvent.

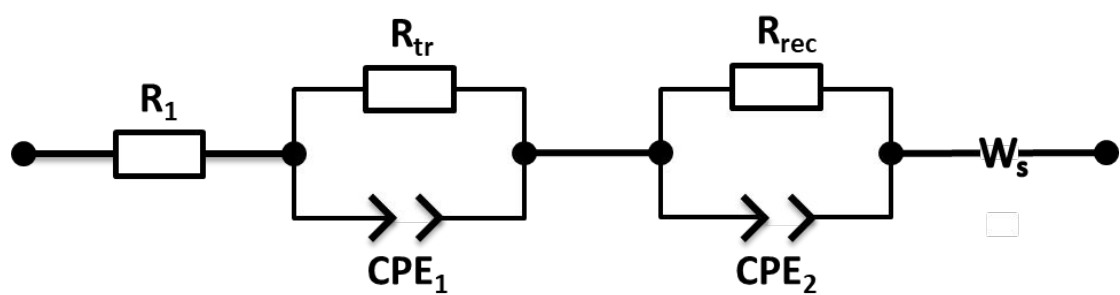


Figure S7. Equivalent circuit diagram used to fit the Nyquist plots.

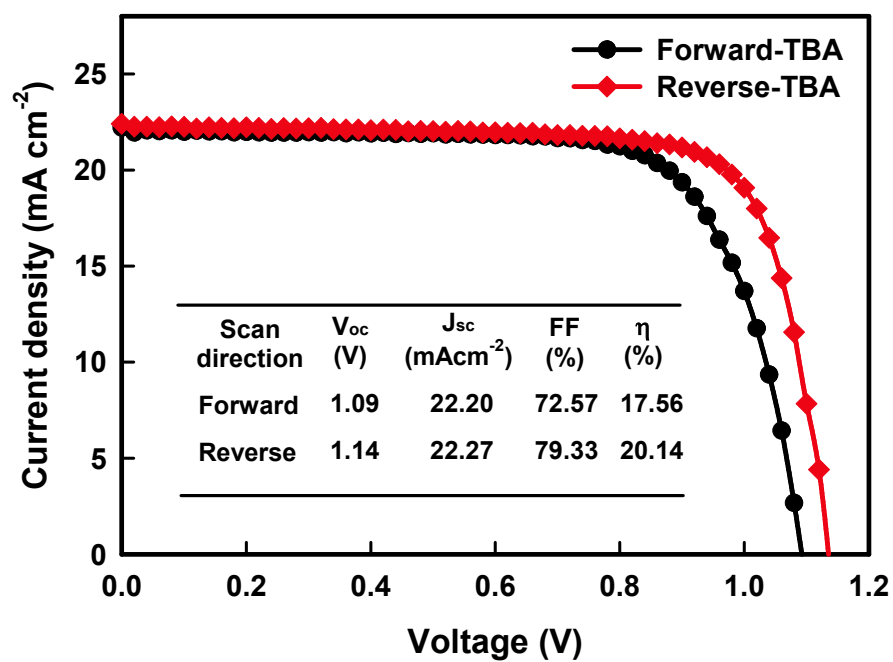


Figure S8. J–V curves for PSC on glass/ ITO based on SnO_2 -TBA under different scan directions. PSCs were fabricated by CB anti-solvent.

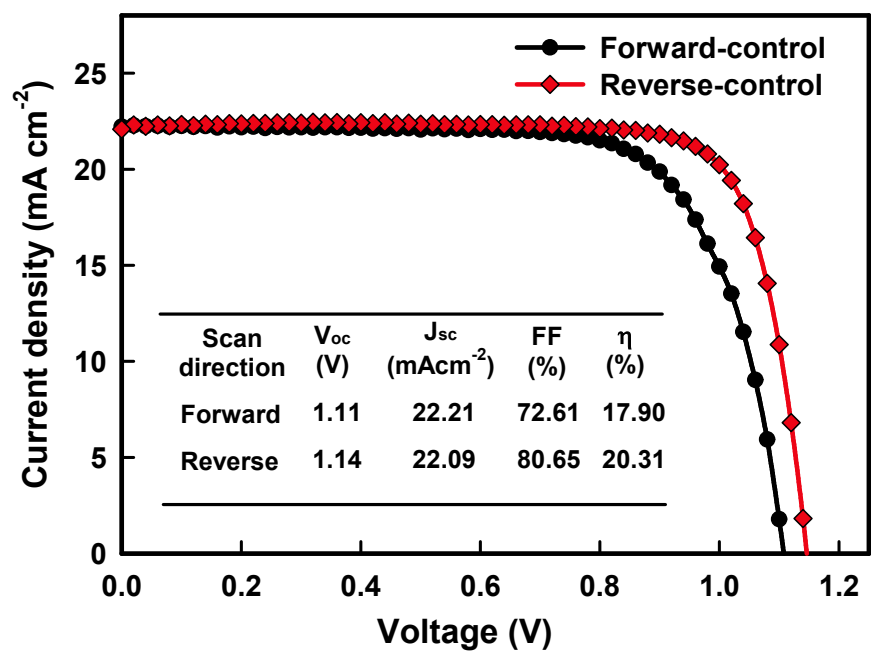


Figure S9. J–V curves for PSC on glass/ ITO based on SnO_2 -control under different scan directions. The glass/ ITO substrate was treated by UVO for 15 min just before the deposition of SnO_2 ETL. PSCs were fabricated by PhOMe green anti-solvent.

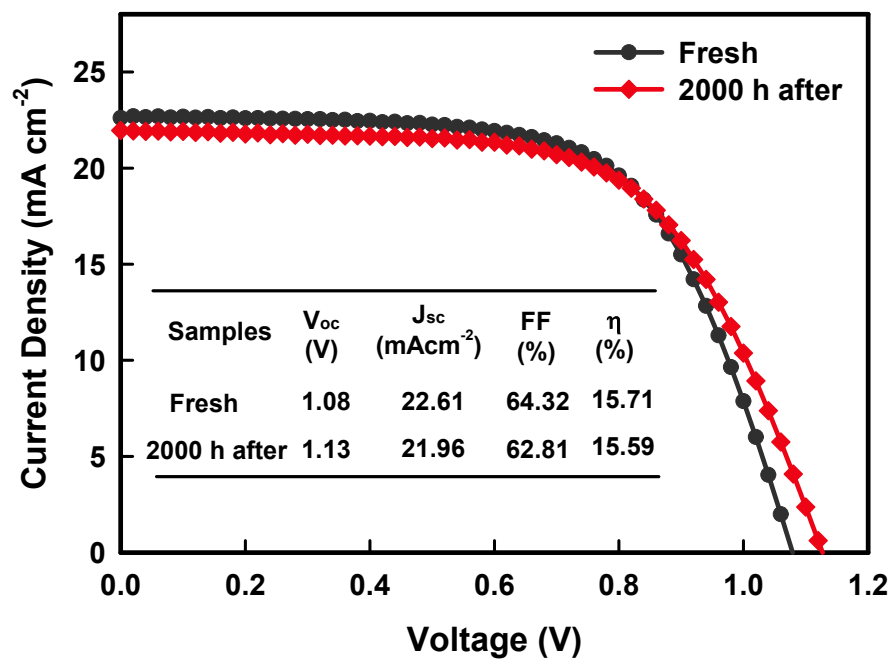


Figure S10. J–V curves of the flexible PSC for fresh device and PSC after 2000 h dark storage in ambient air (~20% RH) without encapsulation.